

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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### DSA50C150HB

preliminary

 $V_{RRM} = 150V$ 

 $I_{FAV} = 2x \quad 25A$ 

 $V_F = 0.74V$ 

Schottky Diode Gen<sup>2</sup>

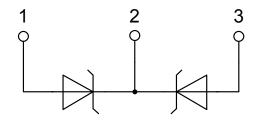
High Performance Schottky Diode Low Loss and Soft Recovery Common Cathode

Part number

DSA50C150HB



Backside: cathode



#### Features / Advantages:

- Very low Vf
- Extremely low switching losses
- Low Irm values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

#### **Applications:**

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0





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Schottky					Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit	
V <sub>RSM</sub>	max. non-repetitive reverse blocki	ing voltage	$T_{VJ} = 25^{\circ}C$			150	V	
V <sub>RRM</sub>	max. repetitive reverse blocking v	oltage	$T_{VJ} = 25^{\circ}C$			150	V	
I <sub>R</sub>	reverse current, drain current	V <sub>R</sub> = 150 V	$T_{VJ} = 25^{\circ}C$			450	μΑ	
		$V_R = 150 V$	$T_{VJ} = 125^{\circ}C$			5	mΑ	
V <sub>F</sub>	forward voltage drop	I <sub>F</sub> = 25 A	$T_{VJ} = 25^{\circ}C$			0.88	V	
		I <sub>F</sub> = 50 A				1.02	V	
		I <sub>F</sub> = 25 A	T <sub>VJ</sub> = 125°C			0.74	V	
		I <sub>F</sub> = 50 A				0.90	V	
I <sub>FAV</sub>	average forward current	T <sub>c</sub> = 155°C	T <sub>vJ</sub> = 175°C			25	Α	
		rectangular d = 0.5					i I I I	
V <sub>F0</sub>	threshold voltage		T <sub>vJ</sub> = 175°C			0.53	V	
r <sub>F</sub>	slope resistance \( \) for power lo	oss calculation only				5.8	mΩ	
R <sub>thJC</sub>	thermal resistance junction to case	е				0.95	K/W	
R <sub>thCH</sub>	thermal resistance case to heatsing	nk			0.25		K/W	
P <sub>tot</sub>	total power dissipation		$T_{\rm C}$ = 25°C			160	W	
I <sub>FSM</sub>	max. forward surge current	$t = 10 \text{ ms}$ ; (50 Hz), sine; $V_R = 0 \text{ V}$	$T_{VJ} = 45^{\circ}C$			390	Α	
C¹	junction capacitance	V <sub>R</sub> = 24 V f = 1 MHz	$T_{VJ} = 25^{\circ}C$		161		pF	

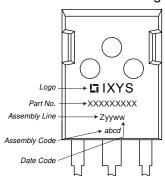


# DSA50C150HB

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Package TO-247				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
I <sub>RMS</sub>	RMS current	per terminal 1)			50	Α	
T <sub>VJ</sub>	virtual junction temperature		-55		175	°C	
T <sub>op</sub>	operation temperature		-55		150	°C	
T <sub>stg</sub>	storage temperature		-55		150	°C	
Weight				6		g	
M <sub>D</sub>	mounting torque		0.8		1.2	Nm	
F <sub>c</sub>	mounting force with clip		20		120	N	

### **Product Marking**



#### Part number

D = Diode

S = Schottky Diode

A = low VF

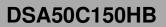
50 = Current Rating [A]

C = Common Cathode

150 = Reverse Voltage [V] HB = TO-247AD (3)

Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSA50C150HB	DSA50C150HB	Tube	30	505450

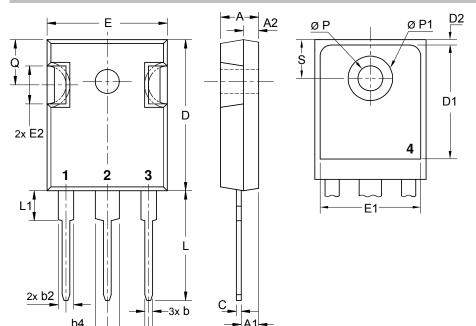
<b>Equivalent Circuits for Simulation</b>			* on die level	$T_{VJ} = 175 ^{\circ}\text{C}$
$I \rightarrow V_0$		Schottky		
V <sub>0 max</sub>	threshold voltage	0.53		V
$R_{0max}$	slope resistance *	3.2		$m\Omega$





preliminary

### Outlines TO-247



Sym.	Inches		Millim	eter
	min.	max.	min.	max.
Α	0.185	0.209	4.70	5.30
A1	0.087	0.102	2.21	2.59
A2	0.059	0.098	1.50	2.49
D	0.819	0.845	20.79	21.45
E	0.610	0.640	15.48	16.24
E2	0.170	0.216	4.31	5.48
е	0.215	BSC	5.46	BSC
L	0.780	0.800	19.80	20.30
L1	-	0.177	-	4.49
ØР	0.140	0.144	3.55	3.65
Q	0.212	0.244	5.38	6.19
S	0.242	BSC	6.14 BSC	
b	0.039	0.055	0.99	1.40
b2	0.065	0.094	1.65	2.39
b4	0.102	0.135	2.59	3.43
С	0.015	0.035	0.38	0.89
D1	0.515	-	13.07	-
D2	0.020	0.053	0.51	1.35
E1	0.530	-	13.45	-
Ø P1	-	0.29	-	7.39

